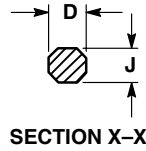
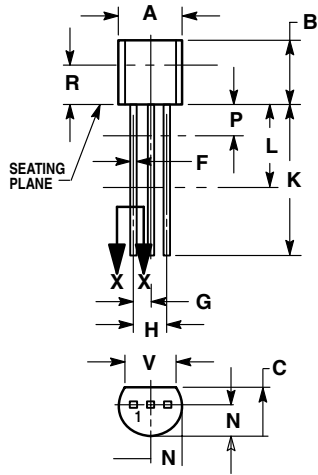


PACKAGE DIMENSIONS



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K. MINIMUM LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

| DIM | INCHES | | MILLIMETERS | |
|-----|--------|-------|-------------|------|
| | MIN | MAX | MIN | MAX |
| A | 0.175 | 0.205 | 4.45 | 5.20 |
| B | 0.170 | 0.210 | 4.32 | 5.33 |
| C | 0.125 | 0.165 | 3.18 | 4.19 |
| D | 0.016 | 0.022 | 0.41 | 0.55 |
| F | 0.016 | 0.019 | 0.41 | 0.48 |
| G | 0.045 | 0.055 | 1.15 | 1.39 |
| H | 0.095 | 0.105 | 2.42 | 2.66 |
| J | 0.015 | 0.020 | 0.39 | 0.50 |
| K | 0.500 | — | 12.70 | — |
| L | 0.250 | — | 6.35 | — |
| N | 0.080 | 0.105 | 2.04 | 2.66 |
| P | — | 0.100 | — | 2.54 |
| R | 0.115 | — | 2.93 | — |
| V | 0.135 | — | 3.43 | — |

CASE 029-04
(TO-226AA)
ISSUE AD

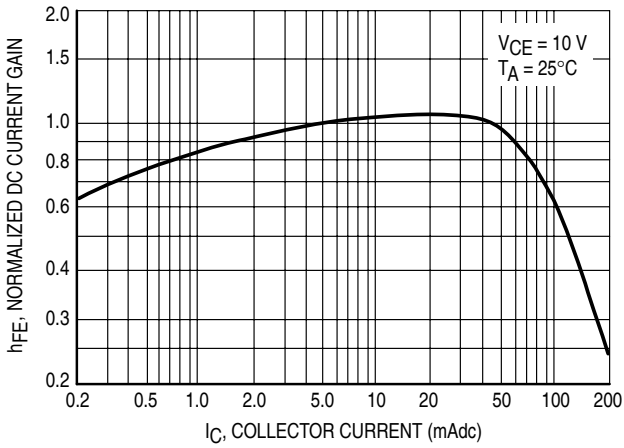


Figure 1. Normalized DC Current Gain

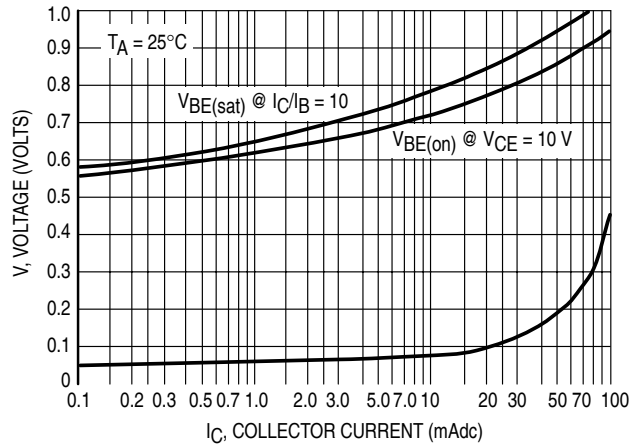


Figure 2. "Saturation" $V_{CE(sat)}$ @ $I_C/I_B = 10$ ges

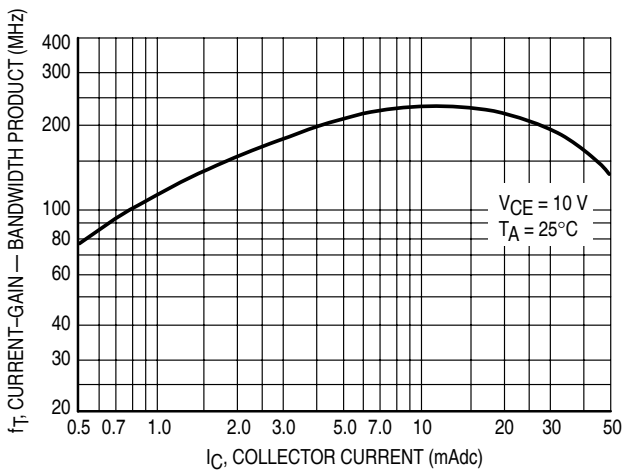


Figure 3. Current-Gain — Bandwidth Product

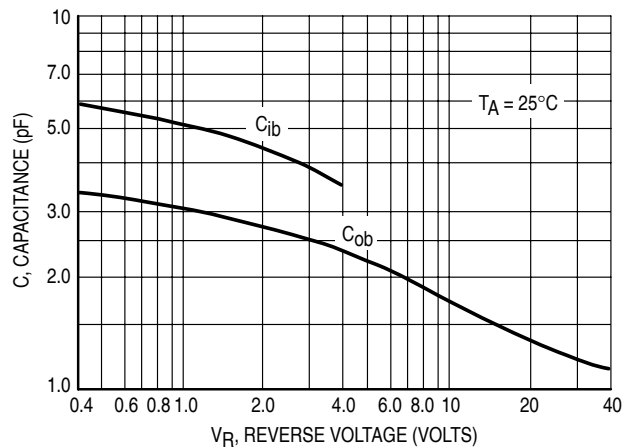


Figure 4. Capacitances

BC237,A,B,C BC238B,C BC239,C

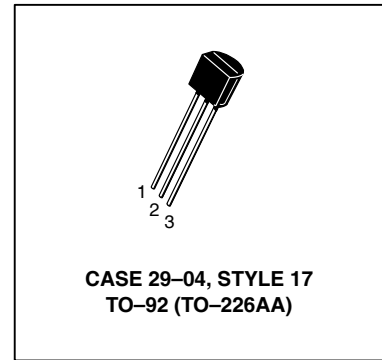
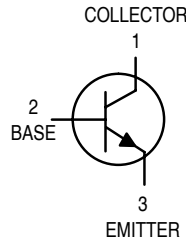
ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|---|---|----------------------|---------------------------------|-----------------------------|---------------------------------|
| ON CHARACTERISTICS | | | | | |
| DC Current Gain ($I_C = 10 \mu\text{A}$, $V_{CE} = 5.0 \text{ V}$) | BC237A BC237B/238B BC237C/238C/239C | hFE | — — — | 90 150 270 | — — — |
| ($I_C = 2.0 \text{ mA}$, $V_{CE} = 5.0 \text{ V}$) | BC237 BC239 BC237A BC237B/238B BC237C/238C/239C | | 120 120 120 200 380 | — — 170 290 500 | 800 800 220 460 800 |
| ($I_C = 100 \text{ mA}$, $V_{CE} = 5.0 \text{ V}$) | BC237A BC237B/238B BC237C/238C/239C | | — — — | 120 180 300 | — — — |
| Collector–Emitter On Voltage ($I_C = 10 \text{ mA}$, $I_B = 0.5 \text{ mA}$) ($I_C = 100 \text{ mA}$, $I_B = 5.0 \text{ mA}$) | BC237/BC238/BC239 BC237/BC239 BC238 | $V_{CE(\text{sat})}$ | — — | 0.07 0.2 | 0.2 0.6 0.8 |
| Base–Emitter Saturation Voltage ($I_C = 10 \text{ mA}$, $I_B = 0.5 \text{ mA}$) ($I_C = 100 \text{ mA}$, $I_B = 5.0 \text{ mA}$) | | $V_{BE(\text{sat})}$ | — — | 0.6 — | 0.83 1.05 |
| Base–Emitter On Voltage ($I_C = 100 \mu\text{A}$, $V_{CE} = 5.0 \text{ V}$) ($I_C = 2.0 \text{ mA}$, $V_{CE} = 5.0 \text{ V}$) ($I_C = 100 \text{ mA}$, $V_{CE} = 5.0 \text{ V}$) | | $V_{BE(\text{on})}$ | — 0.55 — | 0.5 0.62 0.83 | — 0.7 — |
| DYNAMIC CHARACTERISTICS | | | | | |
| Current–Gain — Bandwidth Product ($I_C = 0.5 \text{ mA}$, $V_{CE} = 3.0 \text{ V}$, $f = 100 \text{ MHz}$) | BC237 BC238 BC239 | f_T | — — — | 100 120 140 | — — — |
| ($I_C = 10 \text{ mA}$, $V_{CE} = 5.0 \text{ V}$, $f = 100 \text{ MHz}$) | BC237 BC238 BC239 | | 150 150 150 | 200 240 280 | — — — |
| Collector–Base Capacitance ($V_{CB} = 10 \text{ V}$, $I_C = 0$, $f = 1.0 \text{ MHz}$) | | C_{obo} | — | — | 4.5 |
| Emitter–Base Capacitance ($V_{EB} = 0.5 \text{ V}$, $I_C = 0$, $f = 1.0 \text{ MHz}$) | | C_{ibo} | — | 8.0 | — |
| Noise Figure ($I_C = 0.2 \text{ mA}$, $V_{CE} = 5.0 \text{ V}$, $R_S = 2.0 \text{ k}\Omega$, $f = 1.0 \text{ kHz}$) | BC239 | NF | — | 2.0 | 4.0 |
| ($I_C = 0.2 \text{ mA}$, $V_{CE} = 5.0 \text{ V}$, $R_S = 2.0 \text{ k}\Omega$, $f = 1.0 \text{ kHz}$, $\Delta f = 200 \text{ Hz}$) | BC237 BC238 BC239 | | — — — | 2.0 2.0 2.0 | 10 10 4.0 |

Amplifier Transistors

NPN Silicon

BC237,A,B,C
BC238B,C
BC239,C



MAXIMUM RATINGS

| Rating | Symbol | BC 237 | BC 238 | BC 239 | Unit |
|--|----------------|-------------|--------|--------|----------------------|
| Collector–Emitter Voltage | V_{CEO} | 45 | 25 | 25 | Vdc |
| Collector–Emitter Voltage | V_{CES} | 50 | 30 | 30 | Vdc |
| Emitter–Base Voltage | V_{EBO} | 6.0 | 5.0 | 5.0 | Vdc |
| Collector Current — Continuous | I_C | 100 | | | mAdc |
| Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C | P_D | 350 | | | mW |
| | | 2.8 | | | mW/ $^\circ\text{C}$ |
| Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C | P_D | 1.0 | | | Watts |
| | | 8.0 | | | mW/ $^\circ\text{C}$ |
| Operating and Storage Junction Temperature Range | T_J, T_{stg} | –55 to +150 | | | $^\circ\text{C}$ |

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|---|-----------------|-----|---------------------------|
| Thermal Resistance, Junction to Ambient | $R_{\theta JA}$ | 357 | $^\circ\text{C}/\text{W}$ |
| Thermal Resistance, Junction to Case | $R_{\theta JC}$ | 125 | $^\circ\text{C}/\text{W}$ |

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|----------------|--------|-----|-----|-----|------|
|----------------|--------|-----|-----|-----|------|

OFF CHARACTERISTICS

| | | | | | | |
|---|-------------------------|---------------|-------------------|-------------|-------------|---------------|
| Collector–Emitter Breakdown Voltage ($I_C = 2.0\text{ mA}, I_B = 0$) | BC237 BC238 BC239 | $V_{(BR)CEO}$ | 45 25 25 | — — — | — — — | V |
| Emitter–Base Breakdown Voltage ($I_E = 100\ \mu\text{A}, I_C = 0$) | BC237 BC238 BC239 | $V_{(BR)EBO}$ | 6.0 5.0 5.0 | — — — | — — — | V |
| Collector Cutoff Current ($V_{CE} = 30\text{ V}, V_{BE} = 0$) | BC238 BC239 | I_{CES} | — — | 0.2 0.2 | 15 15 | nA |
| ($V_{CE} = 50\text{ V}, V_{BE} = 0$) | BC237 | | — | 0.2 | 15 | |
| ($V_{CE} = 30\text{ V}, V_{BE} = 0$) $T_A = 125^\circ\text{C}$ | BC238 BC239 | | — — | 0.2 0.2 | 4.0 4.0 | μA |
| ($V_{CE} = 50\text{ V}, V_{BE} = 0$) $T_A = 125^\circ\text{C}$ | BC237 | | — | 0.2 | 4.0 | |